



BC807-16/-25/-40

45V PNP SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Ideally Suited for Automatic Insertion
- Epitaxial Planar Die Construction
- Complementary NPN Types Available (BC817)
- For switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

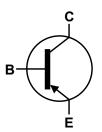
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3
- Weight 0.008 grams (approximate)

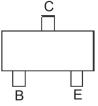


SOT23

Top View



Device Symbol



Top View Pin-Out

Ordering Information (Notes 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BC807-16-7-F	AEC-Q101	K5A	7	8	3,000
BC807-25-7-F	AEC-Q101	K5B	7	8	3,000
BC807-40-7-F	AEC-Q101	K5C	7	8	3,000
BC807-40-13-F	AEC-Q101	K5C	13	8	10,000
BC807-40Q-7-F	Automotive	K5C	7	8	3,000
BC807-40Q-13-F	Automotive	K5C	13	8	10,000

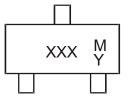
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/. 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



XXX = Product Type Marking Code (See table above) YM = Date Code Marking Y = Year ex: X = 2010 M = Month ex: 9 = September

Date Code Key

Notes:

Year	2010	20	011	2012	2	2013	2014		2015	2016		2017
Code	Х		Y	Z		А	В		С	D		E
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-45	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Continuous Collector Current	I _C	-0.5	A
Peak Collector Current	I _{CM}	-1.0	A
Peak Base Current	I _{BM}	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)	D-	310	mW	
	ation (Note 7) P _D		350		
Thermal Resistance, Junction to Ambient	(Note 6)		403	°C/W	
	(Note 7)	R _{0JA}	357	C/VV	
Thermal Resistance, Junction to Leads (Note 8)		$R_{\theta JL}$	350	°C/W	
Operating and Storage Temperature Range		T _J ,T _{STG}	-55 to +150	°C	

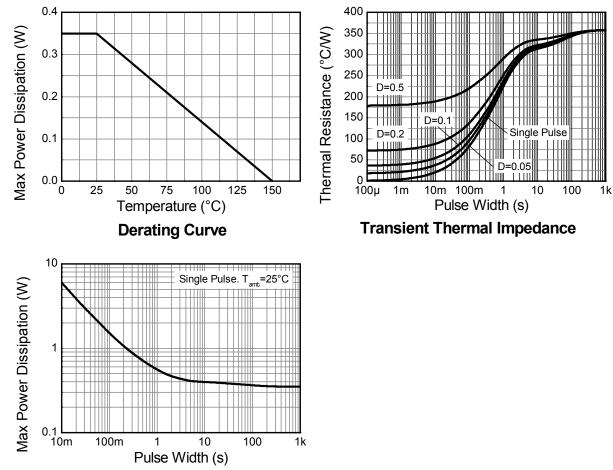
ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

6. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air condition; device Notes: neasured when operating in steady state condition.
Same as Note 6, except the device is mounted on 15mm X 15mm FR4 PCB.
Thermal resistance from junction to solder-point (at the end of the leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



Pulse Power Dissipation



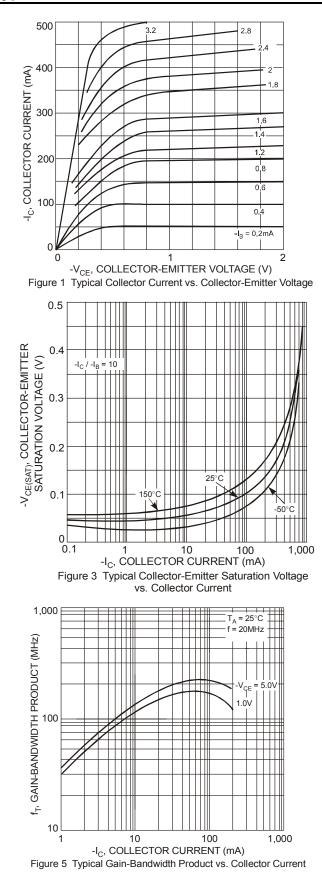
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

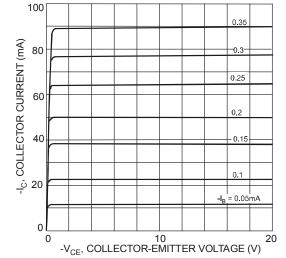
Characteristic			Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV _{CBO}	-50	_	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	-45	_	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage		BV _{EBO}	-5	_	—	V	I _C = -100μA
Collector-Emitter Cutoff Current		ICES	_	_	-100 -5.0	nA μA	V _{CE} = -45V V _{CE} = -25V, T _J = +150°C
Emitter-Base Cutoff Current		I _{EBO}	_	_	-100	nA	V _{EB} = -5.0V
DC Current Gain (Note 10)	BC807-16 BC807-25 BC807-40		100 160 250		250 400 600	_	V _{CE} = -1.0V, I _C = -100mA
	BC807-16 BC807-25 BC807-40	h _{FE}	60 100 170		_		V _{CE} = -1.0V, I _C = -300mA
Collector-Emitter Saturation Volta	age (Note 10)	V _{CE(SAT)}			-0.7	V	I _C = -500mA, I _B = -50mA
Base-Emitter Voltage (Note 10)		V _{BE}			-1.2	V	V _{CE} = -1.0V, I _C = -300mA
Gain Bandwidth Product		f⊤	100	_	_	MHz	V _{CE} = -5.0V, I _C = -10mA, f = 50MHz
Collector-Base Capacitance			_	_	12	pF	V _{CB} = -10V, f = 1.0MHz

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%

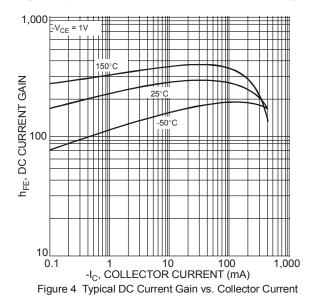


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





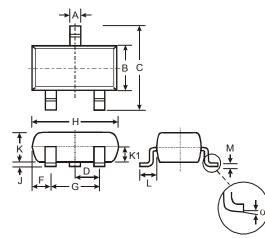






Package Outline Dimensions

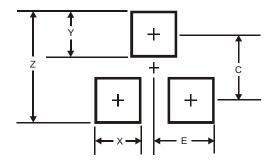
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
К	0.903	1.10	1.00			
K1	-	-	0.400			
L	0.45	0.61	0.55			
М	0.085	0.18	0.11			
α	0°	8°	-			
All	Dimens	ions in	mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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